

GaAs IC SPDT Switch With Integral Driver Non-Reflective DC–6 GHz



AK006M2-01, AK006M2-10

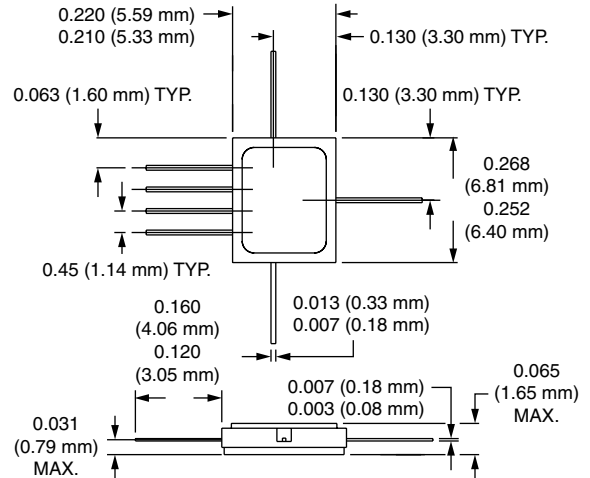
Features

- Integral Driver ± 5 V Supply Voltages
- Non-Reflective, High Isolation
- 7 Lead Hermetic Package
- Capable of Meeting MIL-STD Requirements⁷

Description

The AK006M2-01 is a GaAs IC FET SPDT non-reflective switch with integral driver. These devices are useful in high reliability and commercial applications. The integral driver simplifies the external driver circuit, thus saving PC board space and reducing component count. The AK006M2-10 is the gullwinging version of this device for surface mount applications.

-01



Electrical Specifications at 25°C

Parameter ¹	Frequency ⁶	Min.	Typ.	Max.	Unit
Insertion Loss ²	DC–1.0 GHz		0.8	0.9	dB
	DC–2.0 GHz		1.0	1.1	dB
	DC–4.0 GHz		1.2	1.4	dB
	DC–6.0 GHz		1.6	1.8	dB
Isolation	DC–1.0 GHz	52	55		dB
	DC–2.0 GHz	48	50		dB
	DC–4.0 GHz	37	40		dB
	DC–6.0 GHz	22	25		dB
VSWR (I/O)	DC–1.0 GHz		1.2:1	1.3:1	
	DC–2.0 GHz		1.3:1	1.5:1	
	DC–4.0 GHz		1.6:1	1.8:1	
	DC–6.0 GHz		1.8:1	2.0:1	

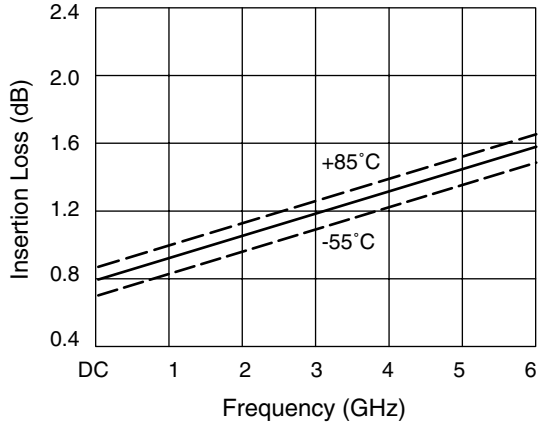
Operating Characteristics at 25°C

Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics	Rise, Fall (10/90% or 90/10% RF)			10	20	ns
	On, Off (50% CTL to 90/10% RF)			20	40	ns
	Video Feedthru ³			30	40	mV
Input Power for 1 dB Compression		0.5–6 GHz	20	23		dBm
		0.001 GHz	12	15		dBm
Intermodulation Intercept Point (IP3)	For Two-tone Input Power 13 dBm	0.5–6 GHz	34	37		dBm
		0.001 GHz	22	26		dBm
Control Voltages	V_{Low}		0		0.5	V
	V_{High}		4		5.5	V
Supply Voltages ^{4,5}	+5 V @ 1 mA Typ.		+4.75		+5.25	V
	-5 V @ 4 mA Typ.		-4.75		-5.25	V

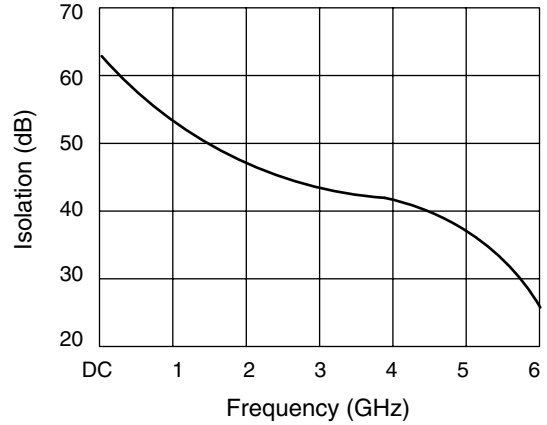
1. All measurements made in a 50 Ω system, unless otherwise specified.
 2. Insertion loss changes by 0.003 dB/°C.
 3. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.
 4. The supply voltage and ground must be connected before TTL voltage is applied. To avoid voltage sequencing refer to the Application Note section, "Driver Protection Circuit."

5. Current increases from 4 mA to 5 mA @ 85°C.
 6. DC = 300 kHz.
 7. See Quality/Reliability section.

Typical Performance Data



Insertion Loss vs. Frequency



Isolation vs. Frequency

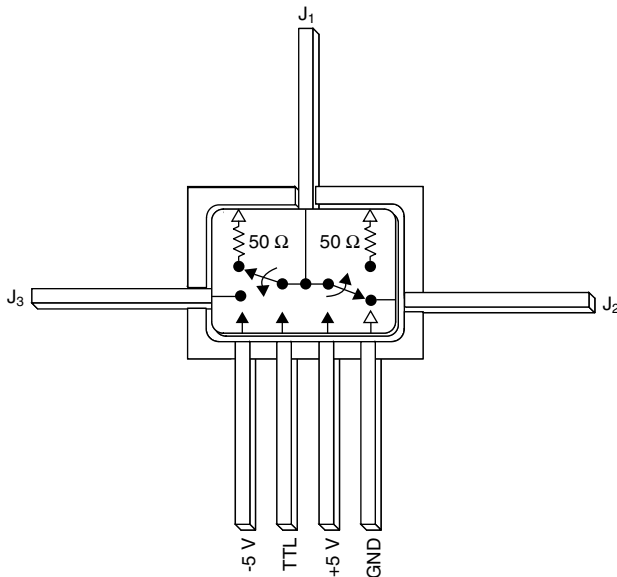
Truth Table

TTL	J ₁ -J ₂	J ₁ -J ₃
1	Insertion Loss	Isolation
0	Isolation	Insertion Loss

Absolute Maximum Ratings

Characteristic	Value
RF Input Power (RF In)	0.5 W > 500 MHz 0.1 W @ 50 MHz
Bias Voltage (V _B)	+7.0 V, -7.0 V
Control Voltage (V _C)	-0.2 V, +7.0 V
Operating Temperature (T _{OP})	-40°C to +90°C
Storage Temperature (T _{ST})	-65°C to +150°C
Thermal Resistance (θ _{JC})	30°C/W

Pin Out



-10

